



DMN2011UFDF

Product Summary

BV _{DSS}	BVDSS RDS(ON) MAX .	
201/	$9.5 m\Omega @ V_{GS} = 4.5 V$	11.7A
201	11mΩ @ V _{GS} = 2.5V	10.8A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions

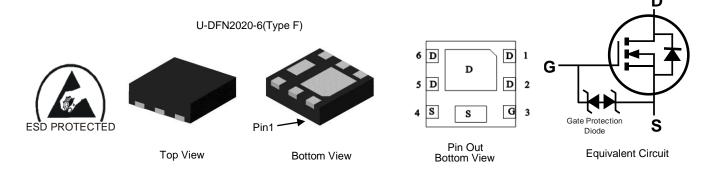
20V N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Low On-Resistance
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0065 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Reel Size (inches)	Quantity per Reel
DMN2011UFDF-7	U-DFN2020-6 (Type F)	7	3,000
DMN2011UFDF-13	U-DFN2020-6 (Type F)	13	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Site 1



N2 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020)M = Month (ex: 9 = September)

Date Code Kev

Year	2016		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	D		Н		J	K	L	М	Ν	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



D5 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2016	 2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	6	 0	1	2	3	4	5	6	7	8	9

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	Х	Y	Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage			Vdss	20	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Noto 6) \/ 4.5\/	Steady State	T _A = +25°C T _A = +70°C	lD	11.7 9.3	А
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	t<10s	T _A = +25°C T _A = +70°C	lo	14.2 11.4	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	%)	•	I _{DM}	80	А
Maximum Body Diode Continuous Current			ls	2.5	A
Avalanche Current (Notes 7) L = 0.1mH	I _{AS}	18	А		
Avalanche Energy (Notes 7) L = 0.1mH		Eas	17	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Total Dawar Dissinction (Note 5)	T _A = +25°C	D-	0.73	W	
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	0.47	vv	
Thermal Desistance, Junction to Ambient (Note 5)	Steady State	D	175	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	RθJA	128		
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	Π-	2.1	W	
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	1.3		
Thermal Resistance Junction to Ambient (Note 6)	Steady State	D	61		
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	RθJA	45	°C/W	
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	9.3		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

			-		11.14	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)				r		I
Drain-Source Breakdown Voltage	BV _{DSS}	20	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current TJ = +25°C	ldss	—	—	1	μA	$V_{DS} = 16V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—	—	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)					-	
Gate Threshold Voltage	V _{GS(TH)}	0.4	—	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
			6.5	9.5		$V_{GS} = 4.5V, I_{D} = 7A$
Static Drain-Source On-Resistance	Design		7.5	11	mΩ	Vgs = 2.5V, ID = 7A
	RDS(ON)		10	20	11152	$V_{GS} = 1.8V, I_D = 5A$
			15	35		Vgs = 1.5V, ID = 3A
Diode Forward Voltage	Vsd	_	0.7	1.2	V	VGS = 0V, IS = 8.5A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	_	2248	—	pF	
Output Capacitance	Coss	_	295	—	pF	Vps = 10V, Vgs = 0V, f = 1.0MHz
Reverse Transfer Capacitance 4	Crss	_	265	—	pF	
Gate Resistance	Rg	_	1.5	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	24	—	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	56	—	nC	V 40V L 0 50
Gate-Source Charge	Q _{gs}	_	3.5	—	nC	V _{DS} = 10V, I _D = 8.5A
Gate-Drain Charge	Qgd	—	5.1	—	nC	
Turn-On Delay Time	t _{D(ON)}	_	3.6	_	ns	
Turn-On Rise Time	t _R		2.6	_	ns	Vps = 10V, Ip = 8.5A
Turn-Off Delay Time	tD(OFF)	—	21.6	—	ns	$V_{GS} = 4.5 V, R_{g} = 1.8 \Omega$
Turn-Off Fall Time	t _F	—	13.5	—	ns	
Reverse Recovery Time	T _{RR}	—	12.8	—	ns	
Reverse Recovery Charge	QRR	—	6.9	—	nC	IF = 8.5A, di/dt = 210A/µs

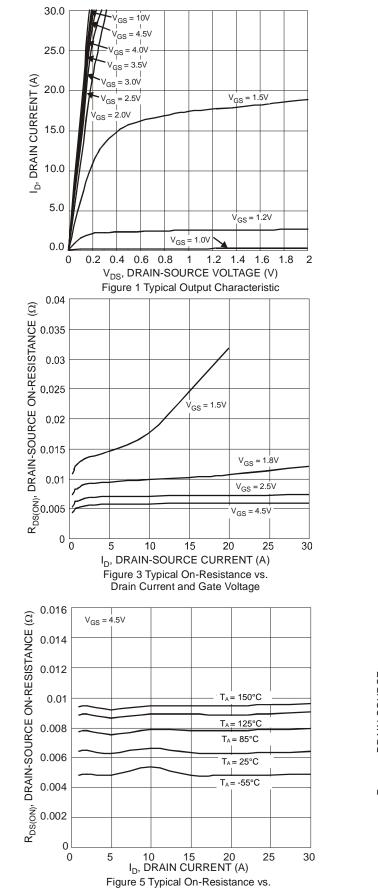
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

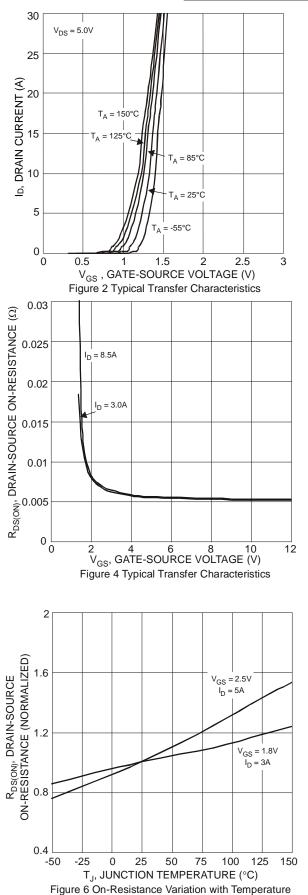
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



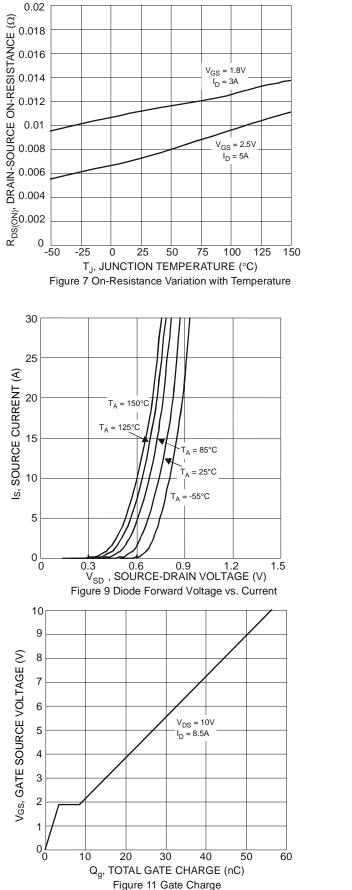


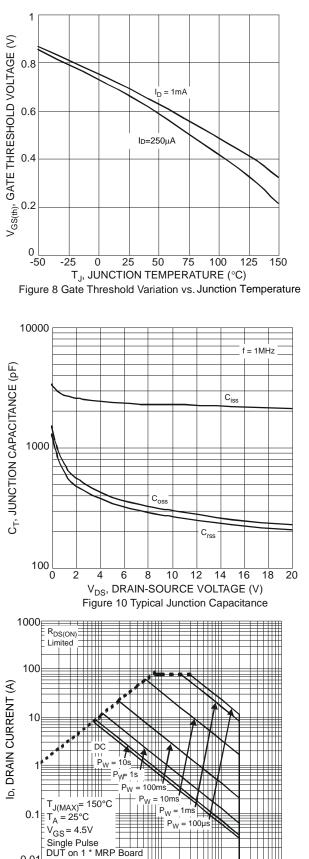
Drain Current and Temperature



DMN2011UFDF



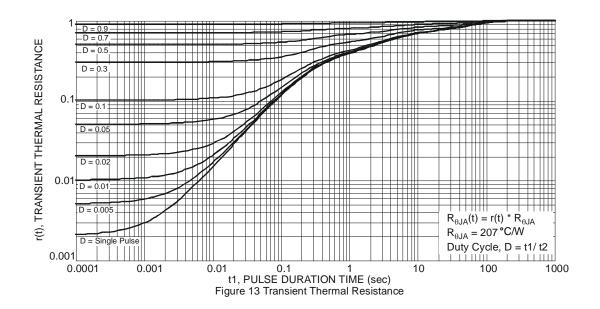




0.01 0.1 1 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12 SOA, Safe Operation Area



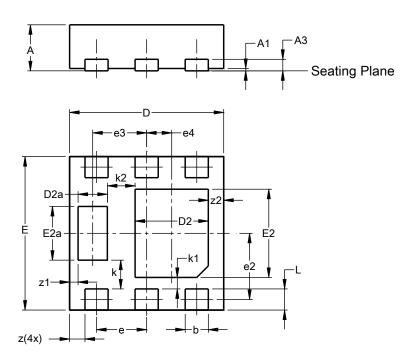






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



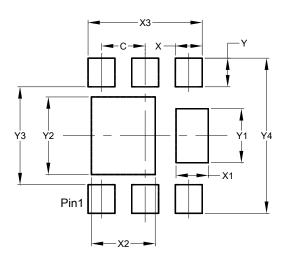
		2020-6				
Dim		be F) Max	Тур			
	Min					
Α	0.57	0.63	0.60			
A1	0.00	0.05	0.03			
A3	-	-	0.15			
b	0.25	0.35	0.30			
D	1.95	2.05	2.00			
D2	0.85	1.05	0.95			
D2a	0.33	0.43	0.38			
E	1.95	2.05	2.00			
E2	1.05	1.25	1.15			
E2a	0.65	0.65 0.75 0				
е	0.65 BSC					
e2	().863 BS	SC			
e3		0.70 BS	С			
e4	().325 BS	SC			
k		0.37 BS	С			
k1		0.15 BS	-			
k2		0.36 BS	С			
L	0.225 0.325 0.275					
z	0.20 BSC					
z1	0).110 BS	SC			
z2		0.20 BS	С			
All D	Dimens	ions in	mm			

U-DFN2020-6 (Type F)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value
Dimensions	(in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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